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|  | <p>SI3456DDV-T1-GE3</p> |
| | <p>Hersteller-Teilenummer: SI3456DDV-T1-GE3</p> <p>Hersteller / Marke: Vishay / Siliconix</p> <p>Teil der Beschreibung: MOSFET N-CH 30V 6.3A 6-TSOP</p> <p>Datenblätter:  SI3456DDV-T1-GE3.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 268186 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p> |
| <p>Image may be representation. See specs for product details.</p> | |

Spezifikationen

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|--|---|
| Teilenummer | SI3456DDV-T1-GE3 |
| Hersteller | Vishay / Siliconix |
| Beschreibung | MOSFET N-CH 30V 6.3A 6-TSOP |
| Kategorie | Diskrete Halbleiterprodukte > Transistoren-FETs, |
| Teilstatus | 268186 pcs Stock |
| Serie | TrenchFET® |
| Technologie | MOSFET (Metal Oxide) |
| Betriebstemperatur | -55°C ~ 150°C (TJ) |
| Befestigungsart | Surface Mount |
| Verpackung / Gehäuse | SOT-23-6 Thin, TSOT-23-6 |
| Supplier Device-Gehäuse | 6-TSOP |
| Verlustleistung (max) | 1.7W (Ta), 2.7W (Tc) |
| Typ FET | N-Channel |
| FET-Merkmal | - |
| Drain-Source-Spannung (Vdss) | 30V |
| Strom - Ununterbrochener Abfluss (Id) bei 25 ° C | 6.3A (Tc) |
| Rds On (Max) @ Id, Vgs | 40 mOhm @ 5A, 10V |
| VGS (th) (Max) @ Id | 3V @ 250µA |
| Gate Charge (Qg) (Max) @ Vgs | 9nC @ 10V |
| Eingabekapazität (Ciss) (Max) @ Vds | 325pF @ 15V |
| Antriebsspannung (Max Rds On, Min Rds On) | 4.5V, 10V |
| Vgs (Max) | ±20V |
| Verpackung | Tape & Reel (TR) |
























SI3456DDV-T1-GE3 ist neu im Original, Suche SI3456DDV-T1-GE3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI3456DDV-T1-GE3 Vishay / Siliconix mit Garantie und Vertrauen. Anfrage SI3456DDV-T1-GE3: Info@Y-IC.com

Sie können auch interessiert sein:

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|  SI3456DV-T1 SILICON SI3456DV-T1 SILICON |  SI3456DDV-T1-GE3 Electro-Films (EFI) / Vishay MOSFET N-CH 30V 6.3A 6-TSOP |  SI3456DV-NL FAIRCHI SI3456DV-NL FAIRCHI |  SI3456DDV-T1-E3 Vishay / Siliconix MOSFET N-CH 30V 6.3A 6TSOP |
|  SI3456CDV-T1-GE3 Vishay / Siliconix MOSFET N-CH 30V 7.7A 6TSOP |  Si3456DDV Vishay Vishay SOT-23-6 |  SI3456DV FAIRCHI SI3456DV FAIRCHI |  SI3456CDV-T1-GE3 Electro-Films (EFI) / Vishay MOSFET N-CH 30V 7.7A 6TSOP |

heiße Teile

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|  SI3454DV-NL |  SI3454DV-T1 |  SI3454DV-T1-E3 |  SI3455ADV-T1-E3 |  SI3455ADV-T1-E3 |
|  SI3455ADV-T1-GE3 |  SI3455ADV-T1-GE3 |  SI3455DV-NL |  SI3455DV-T1-E3 |  SI3455DV-T1-GE3 |
|  SI3456-C02-GU |  SI3456-E04-GU |  SI3456BD-T1-E3 |  SI3456BDV-T1 |  SI3456BDV-T1-E3 |
|  SI3456BDV-T1-E3 |  SI3456BDV-T1-GE3 |  SI3456BDV-T1-GE3 |  SI3456CDV-T1-E3 |  SI3456CDV-T1-E3 |
|  SI3456CDV-T1-GE3 |  SI3456CDV-T1-GE3 |  SI3456DDV-T1-E3 |  SI3456DDV-T1-E3 |  SI3456DDV-T1-GE3 |
|  SI3456DV |  SI3456DV-NL |  SI3456DV-T1 |  SI3456DV-T1-E3 |  SI3456DV-T1-GE3 |
|  SI3457-B02-IT |  SI3457BDV |  SI3457BDV-T1 |  SI3457BDV-T1-E3 |  SI3457BDV-T1-E3 |
|  SI3457BDV-T1-GE3 |  SI3457BDV-T1-GE3 |  SI3457CDV-T1-E3 |  SI3457CDV-T1-E3 |  SI3457CDV-T1-GE3 |
|  SI3457CDV-T1-GE3 |  SI3457DV |  SI3457DV |  SI3457DV-T1 |  SI3457DV-T1-E3 |
|  SI3457DV-T1-GE3 |  SI3457DV-T1-E3 |  SI3458BDV-T1-E3 |  SI3458BDV-T1-E3 |  SI3458BDV-T1-GE3 |

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